

LMV1012 Analog Series: Pre-Amplified IC's for High Gain 2-Wire Microphones

Check for Samples: [LMV1012](#)

FEATURES

- (Typical LMV1012-15, 2.2V supply, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, $V_{IN} = 18\text{ mV}_{PP}$, unless otherwise specified)
- Supply voltage
 - 2V - 5V
- Supply current
 - <180 μA
- Signal to noise ratio (A-weighted)
 - 60 dB
- Output voltage noise (A-weighted)
 - -89 dBV
- Total harmonic distortion
 - 0.09%
- Voltage gain
 - LMV1012-07
 - 7.8 dB

- LMV1012-15
 - 15.6 dB
- LMV1012-20
 - 20.9 dB
- LMV1012-25
 - 23.8 dB
- Temperature range
 - -40°C to 85°C
- Offered in 4-bump micro SMD packages

APPLICATIONS

- Cellular phones
- Headsets
- Mobile communications
- Automotive accessories
- PDAs
- Accessory microphone products

DESCRIPTION

The LMV1012 is an audio amplifier series for small form factor electret microphones. This 2-wire portfolio is designed to replace the JFET amplifier currently being used. The LMV1012 series is ideally suited for applications requiring high signal integrity in the presence of ambient or RF noise, such as in cellular communications. The LMV1012 audio amplifiers are guaranteed to operate over a 2.2V to 5.0V supply voltage range with fixed gains of 7.8 dB, 15.6 dB, 20.9 dB, and 23.8 dB. The devices offer excellent THD, gain accuracy and temperature stability as compared to a JFET microphone.

The LMV1012 series enables a two-pin electret microphone solution, which provides direct pin-to-pin compatibility with the existing JFET market.

The devices are offered in extremely thin space saving 4-bump micro SMD packages. The LMV1012XP is designed for 1.0 mm canisters and thicker ECM canisters. These extremely miniature packages are designed for electret condenser microphones (ECM) form factor.



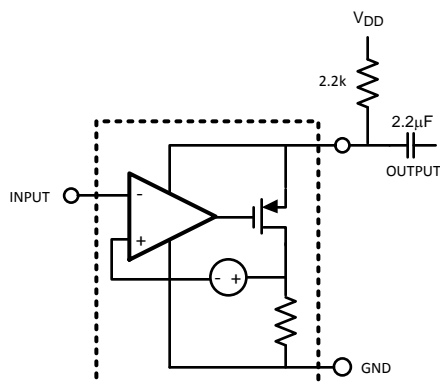
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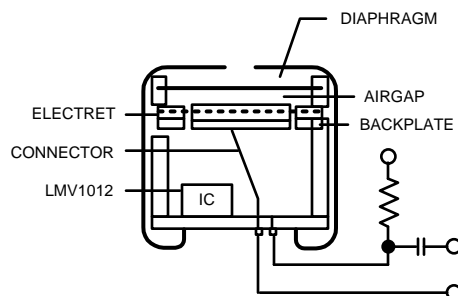
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Schematic Diagram



Built-In Gain Electret Microphone



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾

| | |
|-------------------------------------|----------------|
| ESD Tolerance ⁽²⁾ | |
| Human Body Model | 2500V |
| Machine Model | 250V |
| Supply Voltage | |
| V _{DD} - GND | 5.5V |
| Storage Temperature Range | -65°C to 150°C |
| Junction Temperature ⁽³⁾ | 150°C max |
| Mounting Temperature | |
| Infrared or Convection (20 sec.) | 235°C |

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

(2) Human Body Model (HBM) is 1.5 kΩ in series with 100 pF.

(3) The maximum power dissipation is a function of T_{J(MAX)}, θ_{JA} and T_A. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} - T_A)/θ_{JA}. All numbers apply for packages soldered directly into a PC board.

Operating Ratings ⁽¹⁾

| | |
|-------------------|---------------|
| Supply Voltage | 2V to 5V |
| Temperature Range | -40°C to 85°C |

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

2.2V Electrical Characteristics ⁽¹⁾

Unless otherwise specified, all limits guaranteed for $T_J = 25^\circ\text{C}$, $V_{DD} = 2.2\text{V}$, $V_{IN} = 18\text{ mV}$, $R_L = 2.2\text{ k}\Omega$ and $C = 2.2\text{ }\mu\text{F}$.

Boldface limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | Min (2) | Typ (3) | Max (2) | Units |
|------------|-------------------------------|--|------------|---------------------|------------------------------------|------------------|
| I_{DD} | Supply Current | $V_{IN} = \text{GND}$ | LMV1012-07 | | 139 250 300 | μA |
| | | | LMV1012-15 | | 180 300 325 | |
| | | | LMV1012-20 | | 160 250 300 | |
| | | | LMV1012-25 | | 141 250 300 | |
| SNR | Signal to Noise Ratio | $f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$, A-Weighted | LMV1012-07 | | 59 | dB |
| | | | LMV1012-15 | | 60 | |
| | | | LMV1012-20 | | 61 | |
| | | | LMV1012-25 | | 61 | |
| V_{IN} | Max Input Signal | $f = 1\text{ kHz}$ and $\text{THD+N} < 1\%$ | LMV1012-07 | | 170 | mV_{PP} |
| | | | LMV1012-15 | | 100 | |
| | | | LMV1012-20 | | 50 | |
| | | | LMV1012-25 | | 28 | |
| V_{OUT} | Output Voltage | $V_{IN} = \text{GND}$ | LMV1012-07 | 1.65 1.54 | 1.90 2.03 2.09 | V |
| | | | LMV1012-15 | 1.54 1.48 | 1.81 1.94 2.00 | |
| | | | LMV1012-20 | 1.65 1.55 | 1.85 2.03 2.13 | |
| | | | LMV1012-25 | 1.65 1.49 | 1.90 2.02 2.18 | |
| f_{LOW} | Lower -3dB Roll Off Frequency | $R_{SOURCE} = 50\Omega$ | | | 65 | Hz |
| f_{HIGH} | Upper -3dB Roll Off Frequency | $R_{SOURCE} = 50\Omega$ | | | 95 | kHz |
| e_n | Output Noise | A-Weighted | LMV1012-07 | | -96 | dBV |
| | | | LMV1012-15 | | -89 | |
| | | | LMV1012-20 | | -84 | |
| | | | LMV1012-25 | | -82 | |
| THD | Total Harmonic Distortion | $f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$ | LMV1012-07 | | 0.10 | % |
| | | | LMV1012-15 | | 0.09 | |
| | | | LMV1012-20 | | 0.12 | |
| | | | LMV1012-25 | | 0.15 | |
| C_{IN} | Input Capacitance | | | | 2 | pF |
| Z_{IN} | Input Impedance | | | | >1000 | G Ω |
| A_V | Gain | $f = 1\text{ kHz}$, $R_{SOURCE} = 50\Omega$ | LMV1012-07 | 6.4 5.5 | 7.8 9.5 10.0 | dB |
| | | | LMV1012-15 | 14.0 13.1 | 15.6 16.9 17.5 | |
| | | | LMV1012-20 | 19.5 17.4 | 20.9 22.0 23.3 | |
| | | | LMV1012-25 | 22.5 21.4 | 23.8 25.0 25.7 | |

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

(2) All limits are guaranteed by design or statistical analysis.

(3) Typical values represent the most likely parametric norm.

5V Electrical Characteristics ⁽¹⁾

Unless otherwise specified, all limits guaranteed for $T_J = 25^\circ\text{C}$, $V_{DD} = 5\text{V}$, $V_{IN} = 18\text{ mV}$, $R_L = 2.2\text{ k}\Omega$ and $C = 2.2\text{ }\mu\text{F}$. **Boldface** limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | Min (2) | Typ (3) | Max (2) | Units |
|------------|-------------------------------|--|------------|---------------------|------------------------------------|------------------|
| I_{DD} | Supply Current | $V_{IN} = \text{GND}$ | LMV1012-07 | | 158 250 300 | μA |
| | | | LMV1012-15 | | 200 300 325 | |
| | | | LMV1012-20 | | 188 260 310 | |
| | | | LMV1012-25 | | 160 250 300 | |
| SNR | Signal to Noise Ratio | $f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$, A-Weighted | LMV1012-07 | | 59 | dB |
| | | | LMV1012-15 | | 60 | |
| | | | LMV1012-20 | | 61 | |
| | | | LMV1012-25 | | 61 | |
| V_{IN} | Max Input Signal | $f = 1\text{ kHz}$ and $\text{THD+N} < 1\%$ | LMV1012-07 | | 170 | mV_{PP} |
| | | | LMV1012-15 | | 100 | |
| | | | LMV1012-20 | | 55 | |
| | | | LMV1012-25 | | 28 | |
| V_{OUT} | Output Voltage | $V_{IN} = \text{GND}$ | LMV1012-07 | 4.45 4.38 | 4.65 4.85 | V |
| | | | LMV1012-15 | 4.34 4.28 | 4.56 4.80 | |
| | | | LMV1012-20 | 4.40 4.30 | 4.58 4.75 4.85 | |
| | | | LMV1012-25 | 4.45 4.39 | 4.65 4.83 4.86 | |
| f_{LOW} | Lower -3dB Roll Off Frequency | $R_{SOURCE} = 50\Omega$ | | | 67 | Hz |
| f_{HIGH} | Upper -3dB Roll Off Frequency | $R_{SOURCE} = 50\Omega$ | | | 150 | kHz |
| e_n | Output Noise | A-Weighted | LMV1012-07 | | -96 | dBV |
| | | | LMV1012-15 | | -89 | |
| | | | LMV1012-20 | | -84 | |
| | | | LMV1012-25 | | -82 | |
| THD | Total Harmonic Distortion | $f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$ | LMV1012-07 | | 0.12 | % |
| | | | LMV1012-15 | | 0.13 | |
| | | | LMV1012-20 | | 0.18 | |
| | | | LMV1012-25 | | 0.21 | |
| C_{IN} | Input Capacitance | | | | 2 | pF |
| Z_{IN} | Input Impedance | | | | >1000 | G Ω |
| A_V | Gain | $f = 1\text{ kHz}$, $R_{SOURCE} = 50\Omega$ | LMV1012-07 | 6.4 5.5 | 8.1 10.7 | dB |
| | | | LMV1012-15 | 14.0 13.1 | 15.6 17.5 | |
| | | | LMV1012-20 | 19.2 17.0 | 21.1 23.5 | |
| | | | LMV1012-25 | 22.5 21.2 | 23.9 25.0 25.8 | |

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.
- (2) All limits are guaranteed by design or statistical analysis.
- (3) Typical values represent the most likely parametric norm.

Connection Diagram

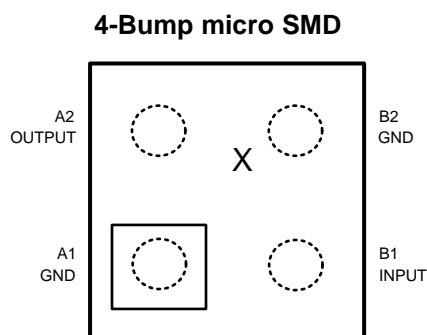


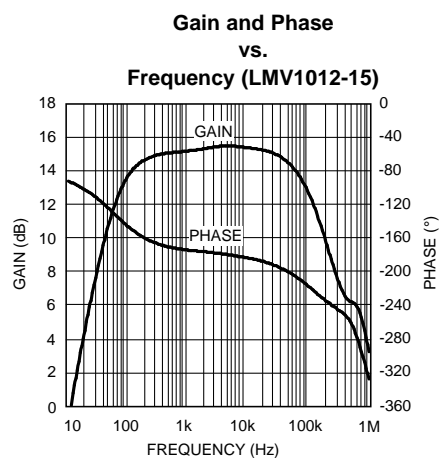
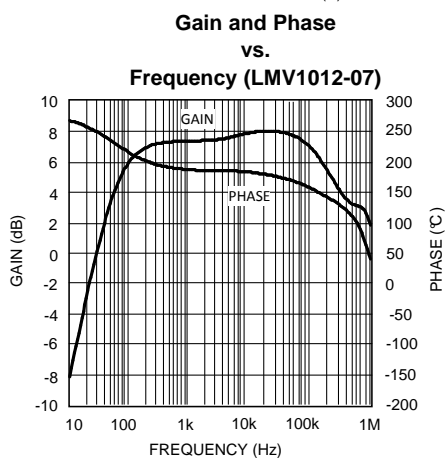
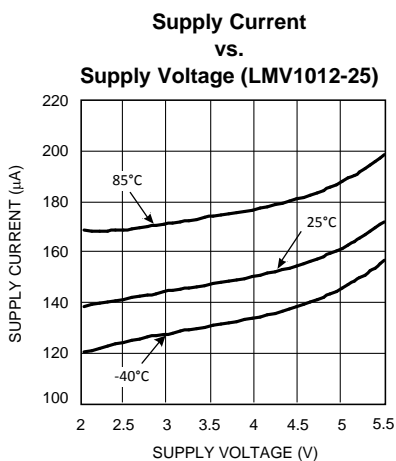
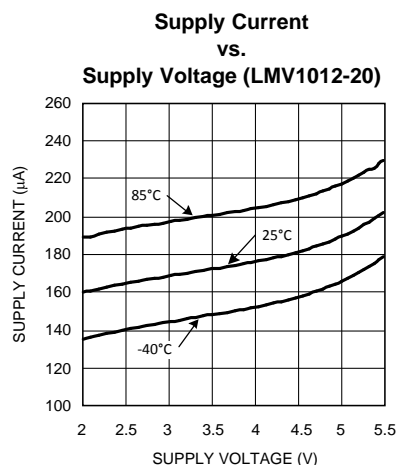
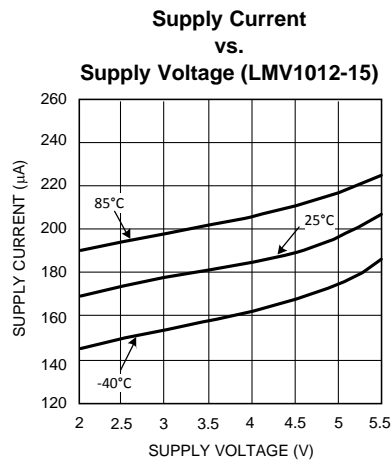
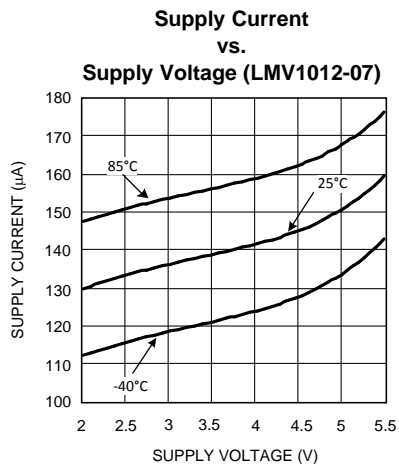
Figure 1. Top View

NOTE

- Pin numbers are referenced to package marking text orientation.
- The actual physical placement of the package marking will vary slightly from part to part. The package will designate the date code and will vary considerably. Package marking does not correlate to device type in any way.

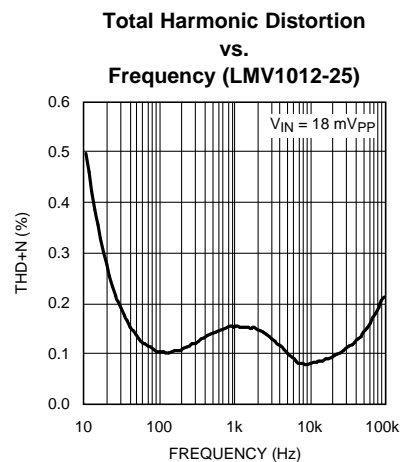
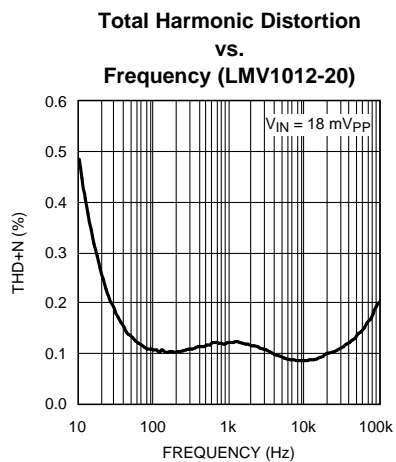
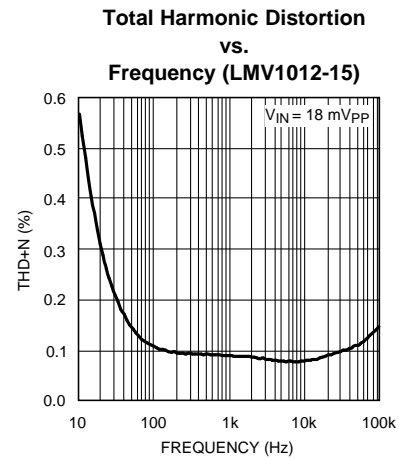
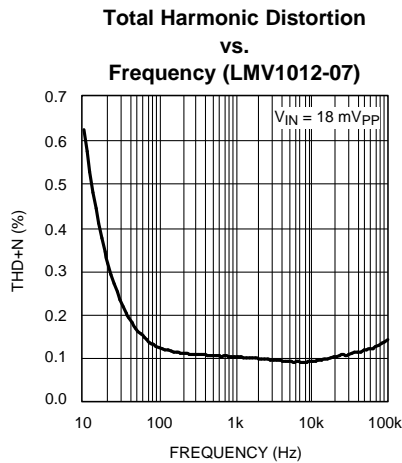
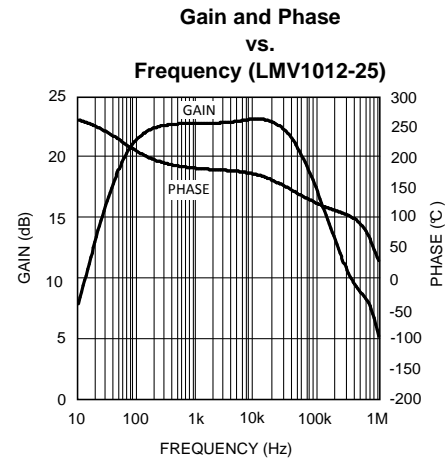
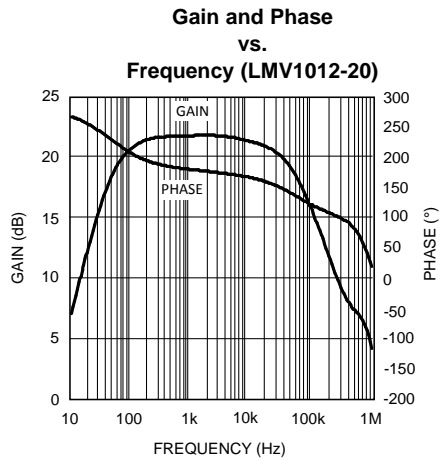
Typical Performance Characteristics

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$



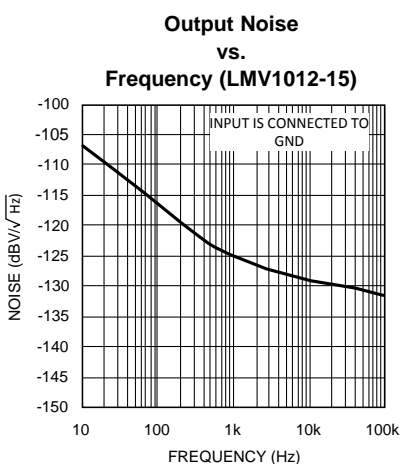
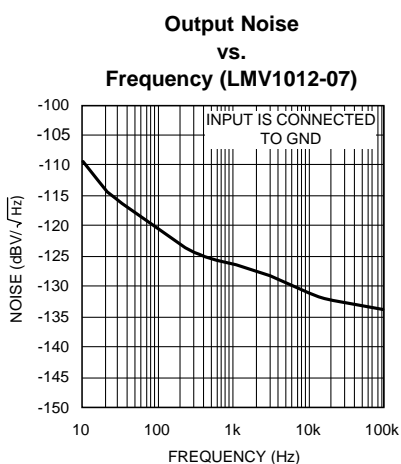
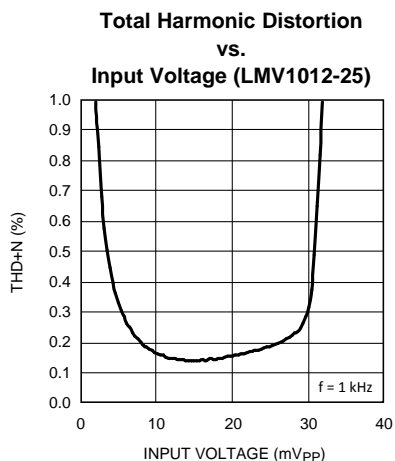
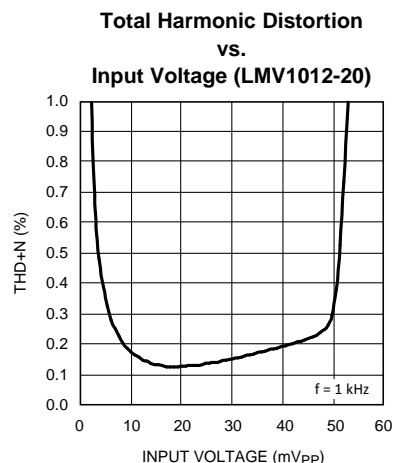
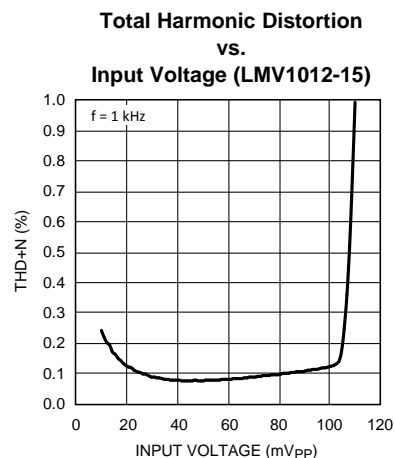
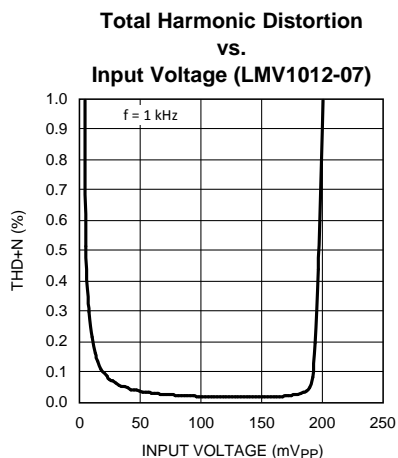
Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$



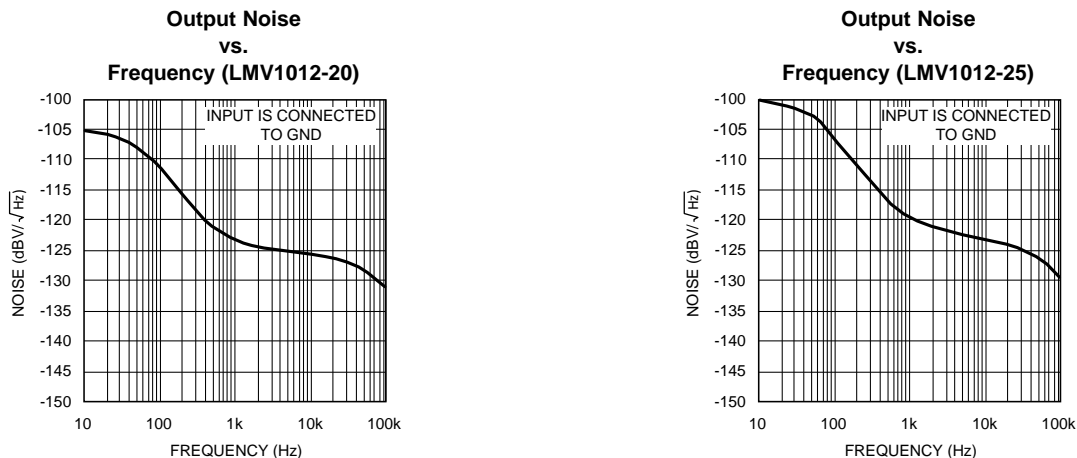
Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2\text{V}$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$



Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$



Application Section

HIGH GAIN

The LMV1012 series provides outstanding gain versus the JFET and still maintains the same ease of implementation, with improved gain, linearity and temperature stability. A high gain eliminates the need for extra external components.

BUILT IN GAIN

The LMV1012 is offered in 0.3 mm height space saving small 4-pin micro SMD packages in order to fit inside the different size ECM canisters of a microphone. The LMV1012 is placed on the PCB inside the microphone.

The bottom side of the PCB usually shows a bull's eye pattern where the outer ring, which is shorted to the metal can, should be connected to the ground. The center dot on the PCB is connected to the V_{DD} through a resistor. This phantom biasing allows both supply voltage and output signal on one connection.

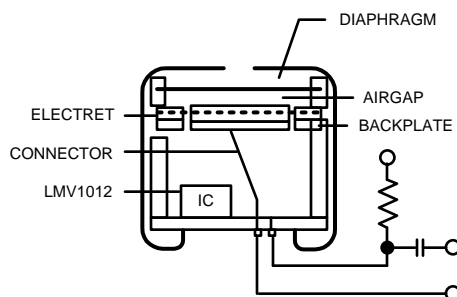
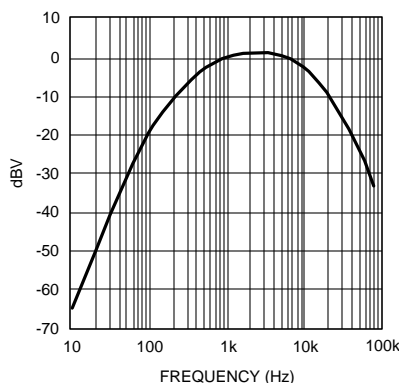


Figure 2. Built in Gain

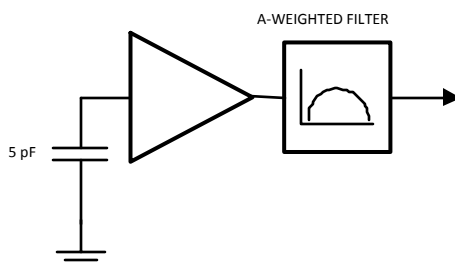
A-WEIGHTED FILTER

The human ear has a frequency range from 20 Hz to about 20 kHz. Within this range the sensitivity of the human ear is not equal for each frequency. To approach the hearing response weighting filters are introduced. One of those filters is the A-weighted filter.

The A-weighted filter is usually used in signal to noise ratio measurements, where sound is compared to device noise. This filter improves the correlation of the measured data to the signal to noise ratio perceived by the human ear.

**Figure 3. A-Weighted Filter****MEASURING NOISE AND SNR**

The overall noise of the LMV1012 is measured within the frequency band from 10 Hz to 22 kHz using an A-weighted filter. The input of the LMV1012 is connected to ground with a 5 pF capacitor, as in Figure 4. Special precautions in the internal structure of the LMV1012 have been taken to reduce the noise on the output.

**Figure 4. Noise Measurement Setup**

The signal to noise ratio (SNR) is measured with a 1 kHz input signal of 18 mV_{pp} using an A-weighted filter. This represents a sound pressure level of 94 dB SPL. No input capacitor is connected for the measurement.

SOUND PRESSURE LEVEL

The volume of sound applied to a microphone is usually stated as a pressure level referred to the threshold of hearing of the human ear. The sound pressure level (SPL) in decibels is defined by:

$$\text{Sound pressure level (dB)} = 20 \log P_m / P_O$$

Where,

P_m is the measured sound pressure

P_O is the threshold of hearing (20 μ Pa)

In order to be able to calculate the resulting output voltage of the microphone for a given SPL, the sound pressure in dB SPL needs to be converted to the absolute sound pressure in dBPa. This is the sound pressure level in decibels referred to 1 Pascal (Pa).

The conversion is given by:

$$\text{dBPa} = \text{dB SPL} + 20 \log 20 \mu\text{Pa}$$

$$\text{dBPa} = \text{dB SPL} - 94 \text{ dB}$$

Translation from absolute sound pressure level to a voltage is specified by the sensitivity of the microphone. A conventional microphone has a sensitivity of -44 dBV/Pa.

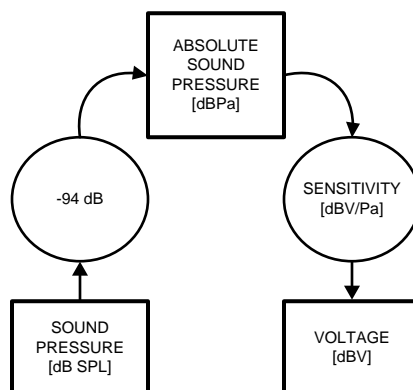


Figure 5. dB SPL to dBV Conversion

Example: Busy traffic is 70 dB SPL

$$V_{OUT} = 70 - 94 - 44 = -68 \text{ dBV}$$

This is equivalent to 1.13 mV_{PP}

Since the LMV1012-15 has a gain of 6 (15.6 dB) over the JFET, the output voltage of the microphone is 6.78 mV_{PP}. By implementing the LMV1012-15, the sensitivity of the microphone is -28.4 dBV/Pa (-44 + 15.6).

LOW FREQUENCY CUT OFF FILTER

To reduce noise on the output of the microphone a low frequency cut off filter has been implemented. This filter reduces the effect of wind and handling noise.

It's also helpful to reduce the proximity effect in directional microphones. This effect occurs when the sound source is very close to the microphone. The lower frequencies are amplified which gives a bass sound. This amplification can cause an overload, which results in a distortion of the signal.

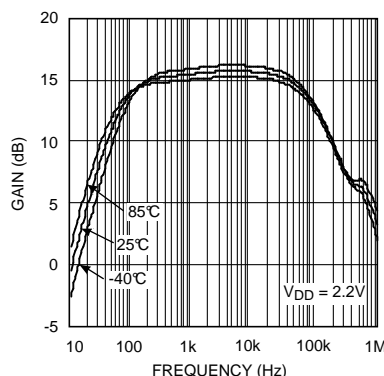


Figure 6. LMV1012-15 Gain vs. Frequency Over Temperature

The LMV1012 is optimized to be used in audio band applications. By using the LMV1012, the gain response is flat within the audio band and has linearity and temperature stability [Figure 6](#).

NOISE

Noise pick-up by a microphone in cell phones is a well-known problem. A conventional JFET circuit is sensitive for noise pick-up because of its high output impedance, which is usually around 2.2 kΩ.

RF noise is amongst other caused by non-linear behavior. The non-linear behavior of the amplifier at high frequencies, well above the usable bandwidth of the device, causes AM-demodulation of high frequency signals. The AM modulation contained in such signals folds back into the audio band, thereby disturbing the intended microphone signal. The GSM signal of a cell phone is such an AM-modulated signal. The modulation frequency of 216 Hz and its harmonics can be observed in the audio band. This kind of noise is called bumblebee noise.

RF noise caused by a GSM signal can be reduced by connecting two external capacitors to ground, see [Figure 7](#). One capacitor reduces the noise caused by the 900 MHz carrier and the other reduces the noise caused by 1800/1900 MHz.

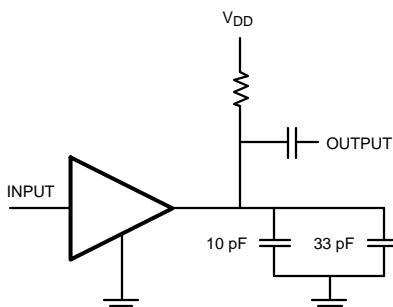


Figure 7. RF Noise Reduction

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish | MSL Peak Temp (3) | Op Temp (°C) | Top-Side Markings (4) | Samples |
|--------------------|---------------|--------------|--------------------|------|-------------|----------------------------|------------------|----------------------|--------------|--------------------------|-------------------------|
| LMV1012TP-07/NOPB | ACTIVE | DSBGA | YPB | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012TP-15/NOPB | ACTIVE | DSBGA | YPB | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012TP-25/NOPB | ACTIVE | DSBGA | YPB | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012TPX-15/NOPB | ACTIVE | DSBGA | YPB | 4 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | | Samples |
| LMV1012TPX-25/NOPB | ACTIVE | DSBGA | YPB | 4 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | | Samples |
| LMV1012UP-07/NOPB | ACTIVE | DSBGA | YPC | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012UP-15/NOPB | ACTIVE | DSBGA | YPC | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012UP-20/NOPB | ACTIVE | DSBGA | YPC | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012UP-25/NOPB | ACTIVE | DSBGA | YPC | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012UPX-07/NOPB | ACTIVE | DSBGA | YPC | 4 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | | Samples |
| LMV1012UPX-15/NOPB | ACTIVE | DSBGA | YPC | 4 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012UPX-20/NOPB | ACTIVE | DSBGA | YPC | 4 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012UPX-25/NOPB | ACTIVE | DSBGA | YPC | 4 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | | Samples |
| LMV1012XP-15/NOPB | ACTIVE | DSBGA | YPE | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012XP-25/NOPB | ACTIVE | DSBGA | YPE | 4 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | | | Samples |
| LMV1012XPX-15/NOPB | ACTIVE | DSBGA | YPE | 4 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | | Samples |
| LMV1012XPX-25/NOPB | ACTIVE | DSBGA | YPE | 4 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LMV1012TPX-15/NOPB | DSBGA | YPB | 4 | 3000 | 178.0 | 8.4 | 1.02 | 1.09 | 0.66 | 4.0 | 8.0 | Q1 |
| LMV1012TPX-25/NOPB | DSBGA | YPB | 4 | 3000 | 178.0 | 8.4 | 1.02 | 1.09 | 0.66 | 4.0 | 8.0 | Q1 |
| LMV1012XP-15/NOPB | DSBGA | YPE | 4 | 250 | 178.0 | 8.4 | 1.06 | 1.13 | 0.4 | 4.0 | 8.0 | Q1 |
| LMV1012XP-25/NOPB | DSBGA | YPE | 4 | 250 | 178.0 | 8.4 | 1.06 | 1.13 | 0.4 | 4.0 | 8.0 | Q1 |
| LMV1012XPX-15/NOPB | DSBGA | YPE | 4 | 3000 | 178.0 | 8.4 | 1.06 | 1.13 | 0.4 | 4.0 | 8.0 | Q1 |
| LMV1012XPX-25/NOPB | DSBGA | YPE | 4 | 3000 | 178.0 | 8.4 | 1.06 | 1.13 | 0.4 | 4.0 | 8.0 | Q1 |

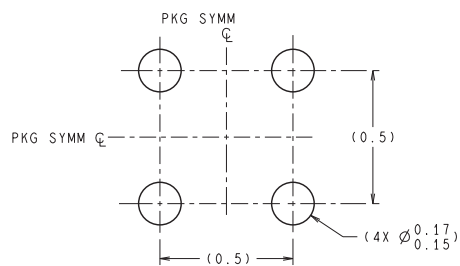
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

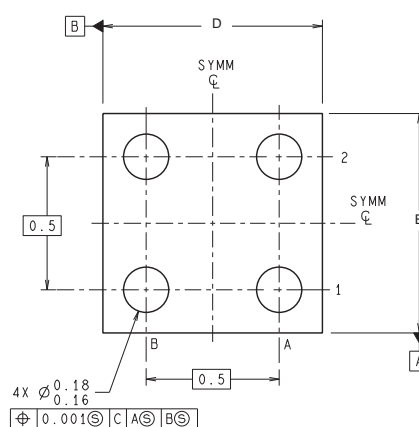
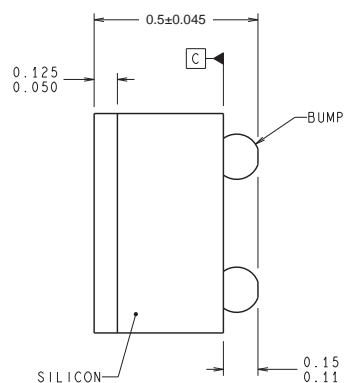
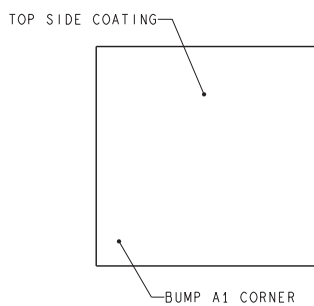
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LMV1012TPX-15/NOPB | DSBGA | YPB | 4 | 3000 | 206.0 | 191.0 | 90.0 |
| LMV1012TPX-25/NOPB | DSBGA | YPB | 4 | 3000 | 206.0 | 191.0 | 90.0 |
| LMV1012XP-15/NOPB | DSBGA | YPE | 4 | 250 | 203.0 | 190.0 | 41.0 |
| LMV1012XP-25/NOPB | DSBGA | YPE | 4 | 250 | 203.0 | 190.0 | 41.0 |
| LMV1012XPX-15/NOPB | DSBGA | YPE | 4 | 3000 | 206.0 | 191.0 | 90.0 |
| LMV1012XPX-25/NOPB | DSBGA | YPE | 4 | 3000 | 206.0 | 191.0 | 90.0 |

YPB0004



DIMENSIONS ARE IN MILLIMETERS

LAND PATTERN RECOMMENDATION



TPA04XXX (Rev B)

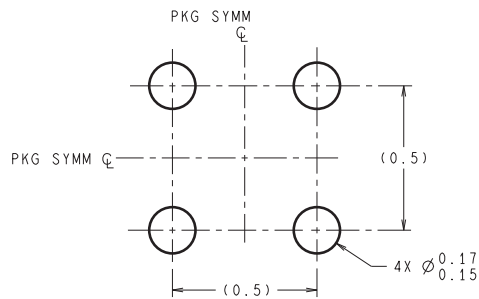
D: Max = 1.077 mm, Min = 0.976 mm

E: Max = 1.001 mm, Min = 0.9 mm

4215097/A 12/12

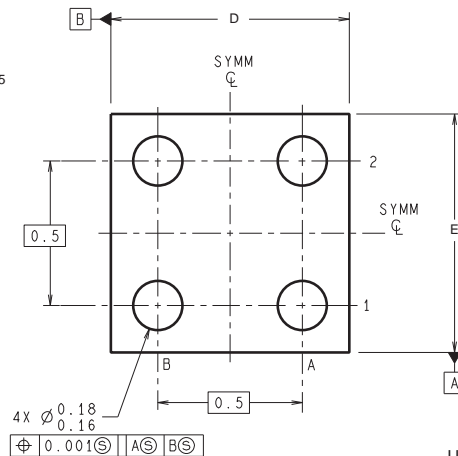
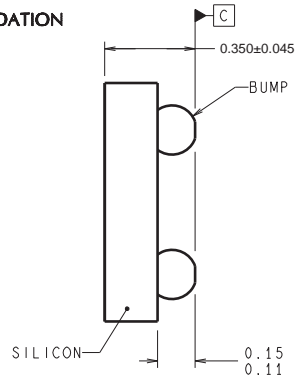
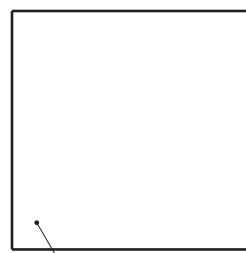
NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

YPC0004



DIMENSIONS ARE IN MILLIMETERS
DIMENSIONS IN () FOR REFERENCE ONLY

LAND PATTERN RECOMMENDATION



UPA04XXX (Rev C)

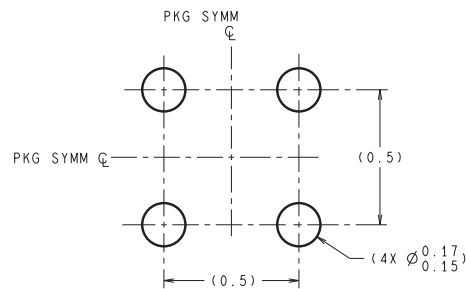
D: Max = 1.077 mm, Min = 0.976 mm

E: Max = 1.001 mm, Min = 0.9 mm

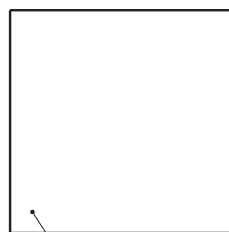
4215139/A 12/12

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

YPE0004

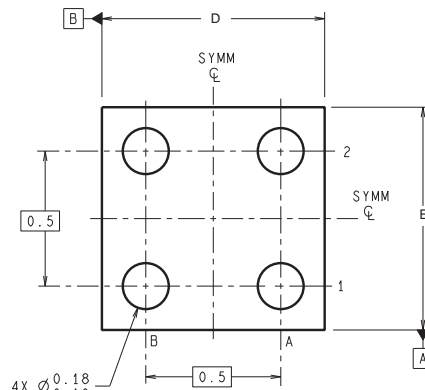
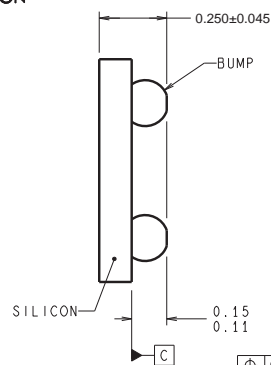


LAND PATTERN RECOMMENDATION



TOP SIDE OF PACKAGE

DIMENSIONS ARE IN MILLIMETERS
DIMENSIONS IN () FOR REFERENCE ONLY



BOTTOM SIDE OF PACKAGE

XPA04XXX (Rev C)

D: Max = 1.077 mm, Min = 0.976 mm

E: Max = 1.001 mm, Min = 0.9 mm

4215203/A 12/12

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
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